

RoHS Compliant

Features:

- High surge current capability
- Void-free plastic in a DO-41 package
- 1A operation at T_A = 55°C with no thermal runaway
- Fast switching for high efficiency
- Exceeds environmental standards of MIL-S-19500/228

Specifications:

Mechanical Data:

Case Terminals Polarity Mounting position Weight Moulded plastic, DO-41
Axial leads, solderable per MIL-STD-202, Method 208
Colour band denotes cathode
Any
0.012 oz, 0.3g

Maximum Ratings and Electrical Characteristics:

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameters	BA157	BA159	Units
Maximum Recurrent Peak Reverse Voltage	400	1,000	
Maximum RMS Voltage	280	700	V
Maximum DC Blocking Voltage	400	1,000	
Maximum Average Forward Rectified Current 0.375" (9.5mm) Lead Length at T _A = 55°C	1		A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	30		
Maximum Forward Voltage at 1A	1.3		V
Maximum reverse current $T_J = 25^{\circ}C$ at rated DC blocking voltage $T_J = 100^{\circ}C$	5 500		μA

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Parameters	BA157	BA159	Units
Typical Junction Capacitance (Note 1)	12		pF
Maximum reverse recovery time (Note 2)	150	250	nS
Operating and Storage Temperature Range	-50 to +150		°C

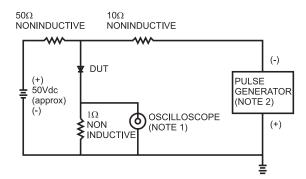
Notes:

1. Measured at 1MHz and applied reverse voltage of 4V.

2. Reverse recovery test conditions: $I_F = 0.5A$, $I_R = 1A$, $I_{RR} = 0.25A$.

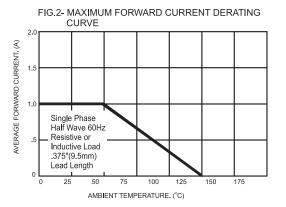
Ratings and Characteristic Curves

Figure 1 - Reverse Recovery Time Characteristics and Test Circuit Diagram

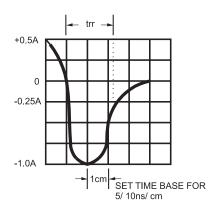


Notes:

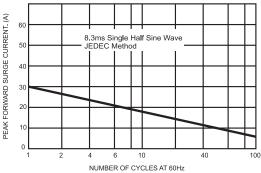
1. Rise Time = 7nS maximum Input Impedance = $1M\Omega$, 22pF 2. Rise Time = 10nS maximum Source Impedance = 50Ω



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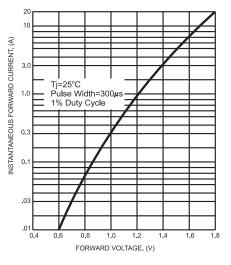




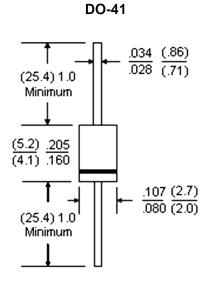












Dimensions : Inches (Millimetres)

Part Number Table

Description	Part Number	
Diode, Fast, 1A, 400V	BA157	
Diode, Fast, 1A, 1,000V	BA159	

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FIG.5- TYPICAL JUNCTION CAPACITANCE

